imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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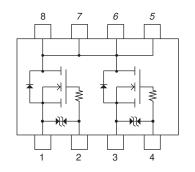
EMH2418R

N-Channel Power MOSFET 24V, 9A, 15mΩ, Dual EMH8



Electrical Connection

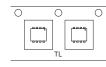
N-channel



Marking



Packing Type:TL



Ordering & Package Information

Device	Package	Shipping		
EMH2418R-TL-H		0.000		
Pb-free and	EMH8	3,000		
Halogen Free		pcs. / reel		

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Features

- Low On-resistance
- 2.5V drive
- Common-Drain Type
- Protection diode in
- Built-in gate protection resistor
- Best suited for LiB charging and discharging switch
- Halogen free compliance

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Value	Unit
Drain to Source Voltage	VDSS	24	V
Gate to Source Voltage	VGSS	±12	V
Drain Current (DC)	۱D	9	А
Drain Current (Pulse)	IDP	40	А
PW≤10μs, duty cycle≤1%			
Power Dissipation	PD	1.3	W
When mounted on ceramic substrate(900mm ² ×0.8mm) 1unit			
Total Dissipation	PT	1.4	W
When mounted on ceramic substrate(900mm ² ×0.8mm)			
JunctionTemperature	Tj	150	°C
Storage Temperature	Tstg	- 55 to	°C
Slorage remperature		+150	

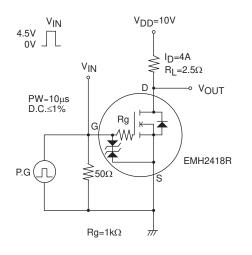
Thermal Resistance Ratings

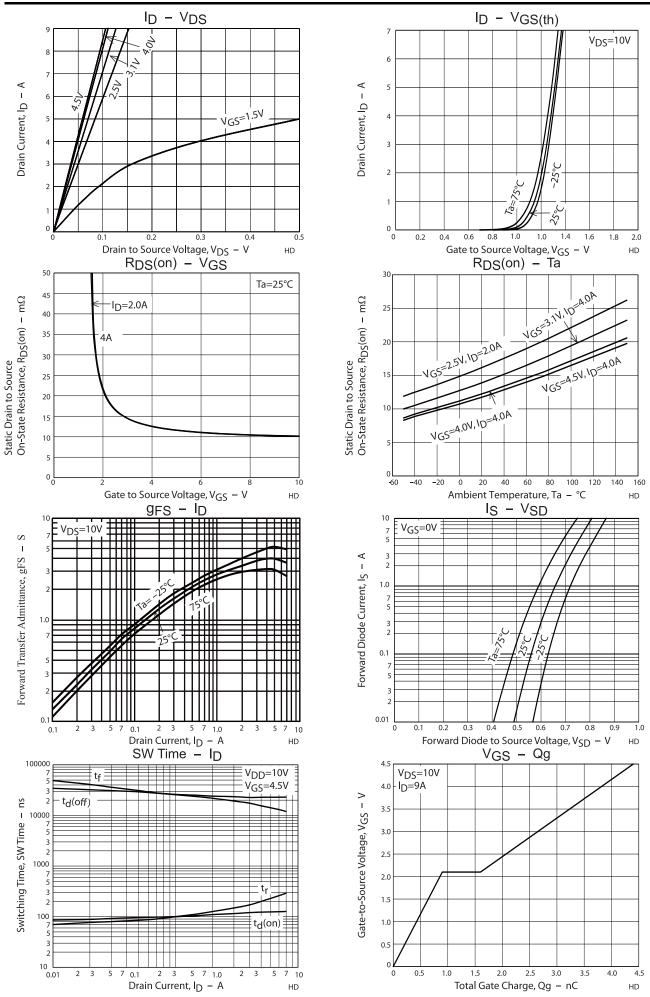
Parameter	Symbol	Value	Unit
Junction to Ambient	$R_{\theta JA}$	96	°C/W
When mounted on ceramic substrate(900mm ² ×0.8mm)			

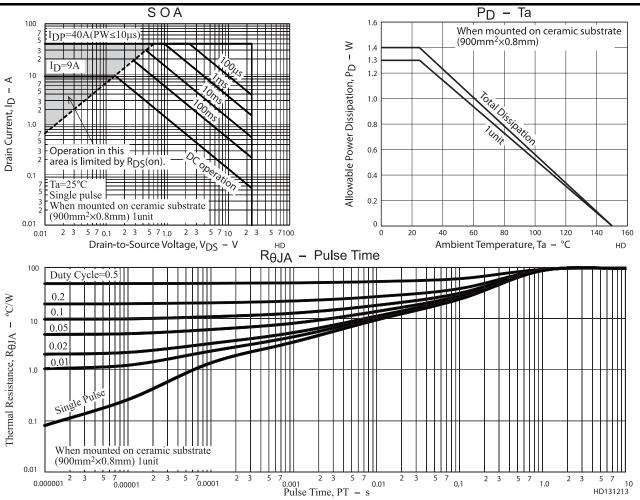
Electrical	Characteristics at $Ta = 25^{\circ}C$
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Parameter		Symbol Conditions	Value			
	Symbol		min	typ	max	Unit
Drain to Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	24			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =20V, V _{GS} =0V			1	μA
Gate to Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0V			±1	μA
Gate Threshold Voltage	V _{GS} (th)	V _{DS} =10V, I _D =1mA	0.5		1.3	V
Forward Transconductance	9FS	V _{DS} =10V, I _D =4A		4		S
	R _{DS} (on)1	I _D =4A, V _{GS} =4.5V	9.6	12	15	mΩ
	R _{DS} (on)2	ID=4A, VGS=4.0V	10.0	12.5	16.3	mΩ
Static Drain to Source On-State Resistance	R _{DS} (on)3	ID=4A, VGS=3.1V	11.3	14.2	20	mΩ
	R _{DS} (on)4	I _D =2A, V _{GS} =2.5V	13.2	16.5	23.1	mΩ
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		120		ns
Rise Time	tr]		170		ns
Turn-OFF Delay Time	t _d (off)]		17500		ns
Fall Time	tf			22600		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =4.5V, I _D =9A		4.4		nC
Gate to Source Charge	Qgs			0.9		nC
Gate to Drain "Miller" Charge	Qgd			0.7		nC
Forward Diode Voltage	V _{SD}	I _S =9A, V _{GS} =0V		0.8	1.2	V

Switching Time Test Circuit

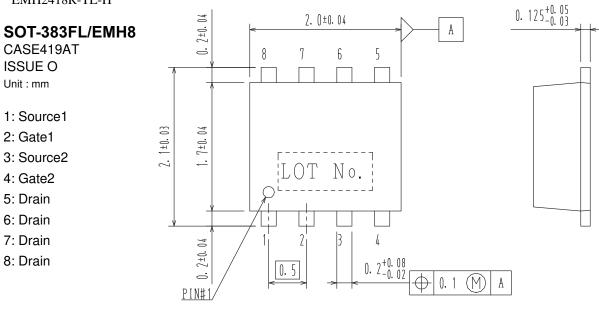


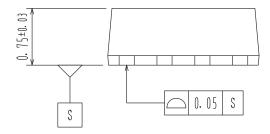




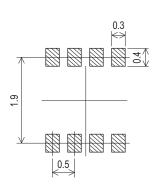
Package Dimensions

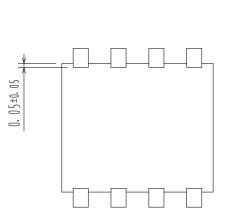
EMH2418R-TL-H











Note on usage : Since the EMH2418R is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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